



ME338 – Manufacturing Process II

Lecture 13 : EBM/LBM/Other NTM

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Few slides have been taken from Prof. Marla and Prof. Rakesh Mote presentations

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Electron Beam Machining (EBM)



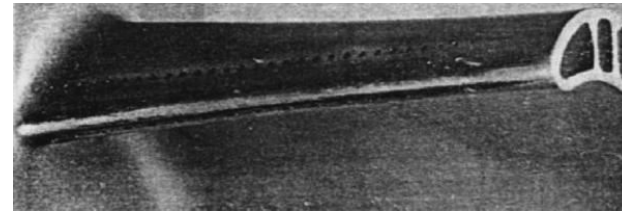
- EBM has been used in nuclear and aerospace welding industries since the early 1960s.
- Drilling small holes, cutting, engraving, and heat treatment are a set of modern applications used in semiconductor manufacturing as well as micromachining areas.
- Used extensively in the preparation of photomasks required in electronics applications.
- EBM is a thermal based process, where high speed electrons impinge on the workpiece.
 - Transfer of kinetic energy into thermal energy
 - Very high electron velocity (200,000 Km/s) can be obtained by using higher voltage (~ 150 kV), resulting into power density $\sim 10^9$ W/mm².
 - Low pressure (10^{-5} mm Hg) working environment is needed to avoid unnecessary collision between electrons and air

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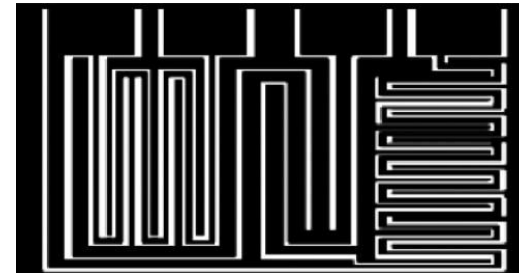
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Applications of EBM



Electron beam–drilled holes in superalloy turbine blade



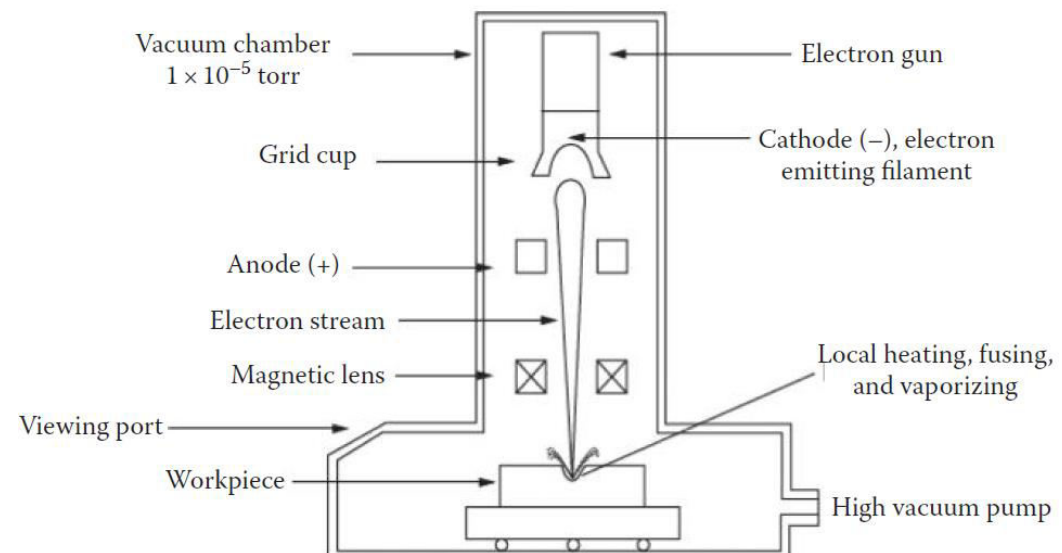
Hybrid circuit engraved with 40 μ m traces at speed >5 m/s.

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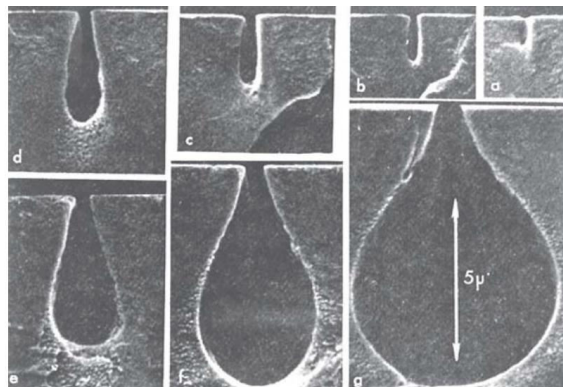
Electron Beam Machining: Schematic



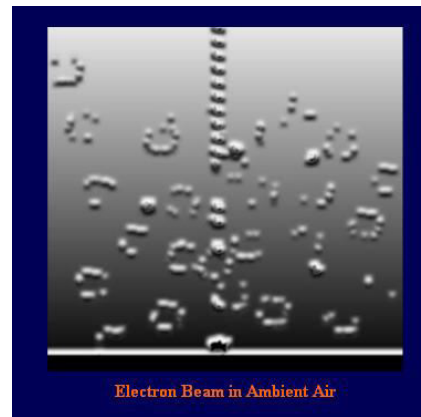
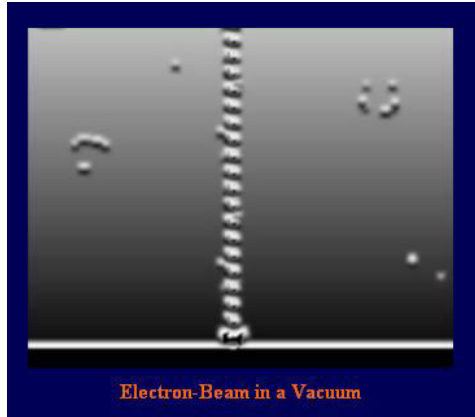
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Why low-pressure environment is needed



The entire process occurs in a vacuum chamber because a collision between an electron and an air molecule causes the electrons to veer off course. LBM doesn't need vacuum because the size and mass of a photon is numerous times smaller than the size of an electron.

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EBM Process Parameters and Capabilities



| EBM Parameter | Level |
|-----------------------|--|
| Acceleration voltage | 50–60 kV |
| Beam current | 100–100 μ A |
| Beam power | 0.5–50 kW |
| Pulse time | 4–64,000 μ s |
| Pulse frequency | 0.1–16,000 Hz |
| Vacuum | 0.01–0.0001 mm mercury |
| Spot size | 0.013–0.025 mm |
| Deflection range | 6.4 mm ² |
| Beam intensity | 1.55×10^5 to 1.55×10^9 W/cm ² |
| Depth of cut | Up to 6.4 mm |
| Narrowest cut | 0.025 mm in 0.025 mm thick metal |
| Hole range | 0.025 mm in 0.02 mm thick metal |
| Hole taper | 1.0 mm in 5 mm thick metal |
| Hole angle to surface | 10–20° typical 20°–90° |
| Removal rate | 40 mm ³ /s ⁻¹ |
| Penetration rate | 0.25 mm/s ⁻¹ |
| Perforation rate | Up to 5,000 holes/s ⁻¹ |
| Tolerance | ±10% depth of cut |
| Surface roughness | 1 μ m R_a |

Source: El-Hofy, H., Advanced Machining Processes, Non-Traditional and Hybrid Processes, McGraw-Hill Book

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EBM Characteristics



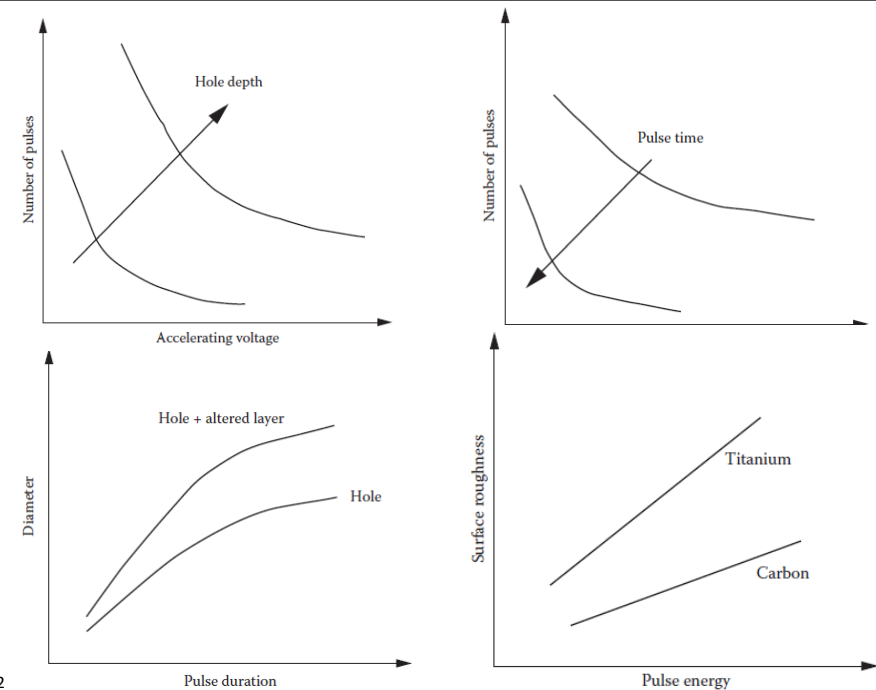
- Mechanics of material removal – melting, vaporization
- Medium – vacuum
- Tool – beam of electrons moving at very high velocity
- Maximum MRR = 10 mm³/min
- Specific power consumption = 450 W/mm³/min
- Critical parameters – accelerating voltage, beam diameter, work speed, melting temperature
- Materials application – all materials
- Shape application – drilling fine holes, cutting contours in sheets, cutting narrow slots
- Limitations – very high specific energy consumption, necessity of vacuum, expensive machine

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Effect of critical process parameters



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- Advantages:
 - Can create smaller, Higher Aspect ratio holes at faster rate in any material irrespective of their properties
 - Provides no limitation to workpiece hardness, ductility, and surface Reflectivity
 - Avoids mechanical distortion to the workpiece because there is no contact
 - Achieves high accuracy and repeatability of ± 0.1 mm for position of holes and $\pm 5\%$ for the hole diameter
 - Smaller HAZ
- Disadvantages
 - High capital equipment cost and maintenance
 - Requirement of vacuum \gg limited size of sample
 - The presence of a thin recast layer in deep holes

Laser beam machining: slot cutting



Laser beam machining (LBM)



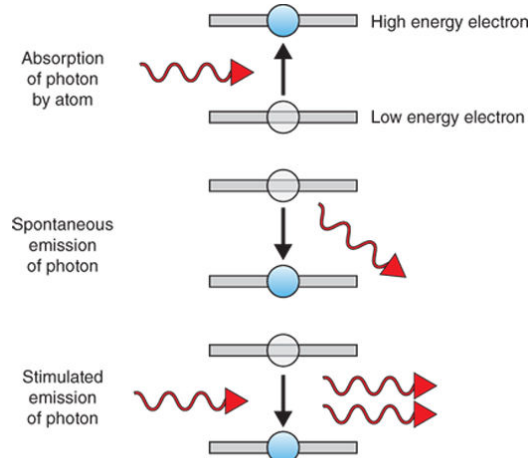
- Laser : A device that emits light through a process of optical amplification based on stimulated emission of electromagnetic radiation.
 - L - Light
 - A - Amplification
 - S - Stimulated
 - E - Emission
 - R – Radiation



Laser : Stimulated Emission



- The concept of stimulated emission was first postulated by Einstein in 1916
- Stimulated emission is the process by which an incoming photon of a specific frequency can interact with an excited atomic electron (or other excited molecular state), causing it to drop to a lower energy level.



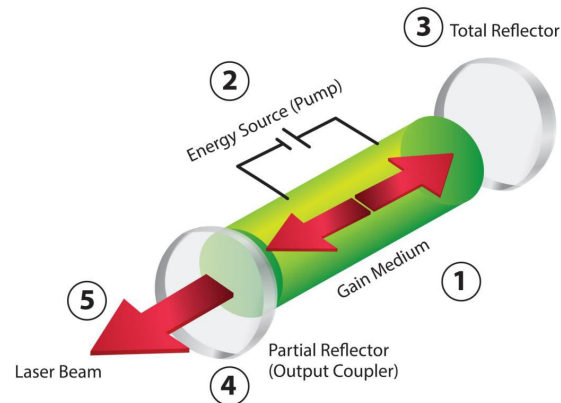
Source: P. Riordan-Eva, J. J. Augsburger: Vaughan & Asbury's General Ophthalmology, Nineteenth Edition Copyright © McGraw-Hill Education. All rights reserved.

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Laser : Operating Principle



- Gain medium capable of sustaining stimulated emission
- Light is amplified in the gain medium
- Light bounces back and forth between the mirrors, passing through the gain medium and being amplified each time

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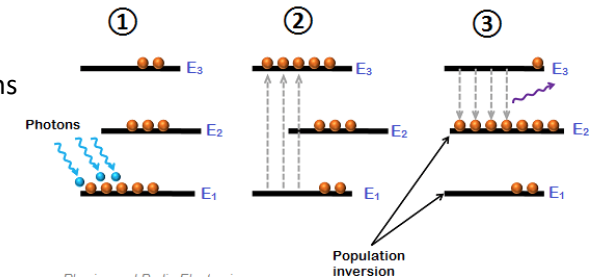
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Laser : Population Inversion



- Under normal conditions, more electrons are in a lower energy state than in a higher energy state.
- Population inversion is a process of achieving more electrons in the higher energy state than the lower energy state.**
 - In order to achieve population inversion, we need to supply energy to the laser medium.
 - The process of supplying energy to the laser medium is called **pumping**.
- Pump sources
 - Optical pumping
 - Electric discharge
 - Inelastic atom-atom collisions
 - Thermal pumping
 - Chemical reactions



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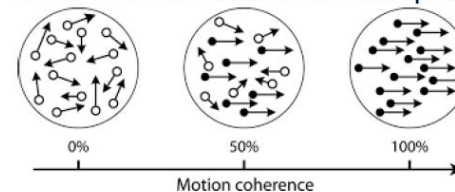
Properties of Laser



- Monochromatic:** Laser light is concentrated in a narrow range of wavelengths



- Coherent:** All the photons bear a constant phase relationship with each other in both time and space



- Directionality:** Laser light is usually low in divergence
- High irradiance:** has very high intensities from 10^9 W/m^2

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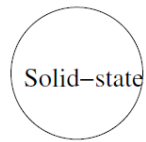
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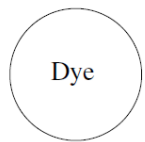
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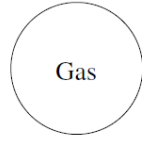
Laser types



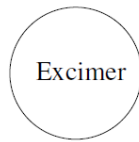
- Ruby
- Nd:YAG
- Fiber
- Semiconductor



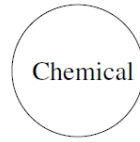
- Rhodamine
- Cuomarin
- Tetracene



- CO₂
- He-Ne
- Ar



- KrF
- XeF



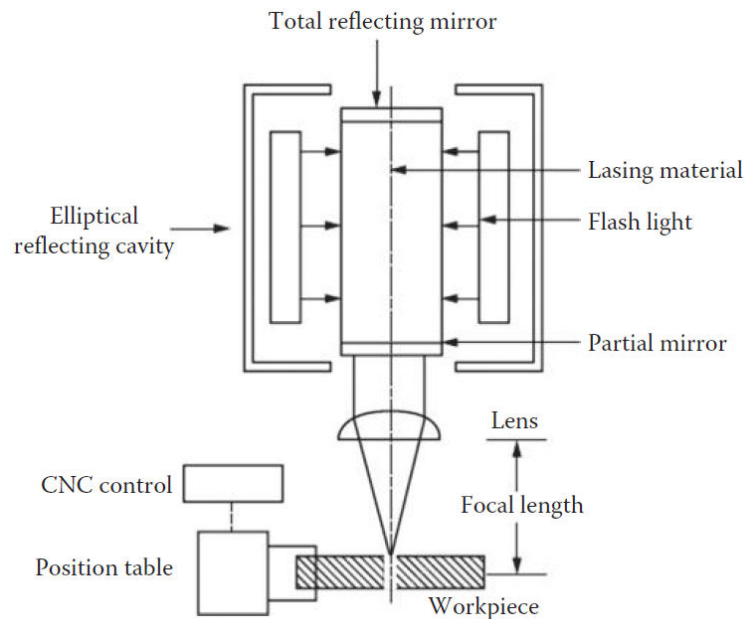
- Oxygen-Iodine
- Gas phase Iodine

• Continuous lasers

• Pulsed Lasers: microsecond - nanosecond - picosecond - femtosecond

Femtosecond laser are required for machining hard materials such as silicon/quartz

Laser beam machining



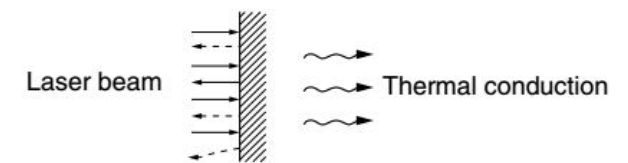
Laser beam machining : Types of Lasers



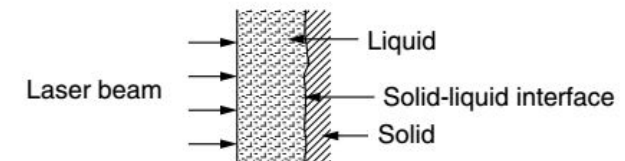
Different Types of Lasers

| Laser Type | | Wavelength (nm) | Typical Performance |
|---------------|-----------------|-----------------|-------------------------|
| Solid | Ruby | 694 | Pulsed, 5 W |
| | Nd-YAG | 1064 | Pulsed, cw, 1-800 W |
| | Nd-glass | 1064 | Pulsed, cw, 2 mW |
| Semiconductor | GaAs | 800-900 | Pulsed, cw, 2-10 mW |
| Molecular | CO ₂ | 10.6 μm | Pulsed, cw, (<15 kW) |
| Ion | Ar ⁺ | 330-530 | Pulsed, cw, 1 W to 5 kW |
| | Excimer | 200-500 | Pulsed |
| Neutral gas | He-Ne | 633 | cw, 20 mW |

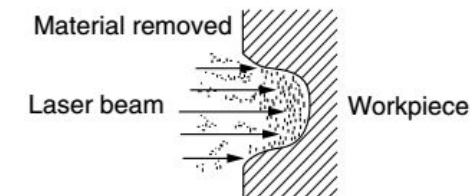
LBM : material removal mechanism



(a) Absorption and heating



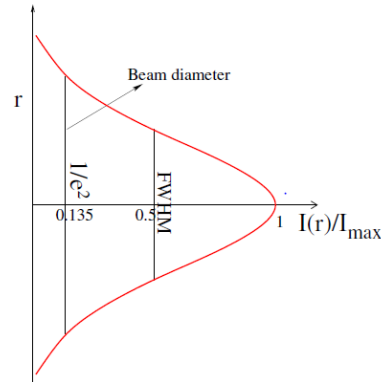
(b) Melting



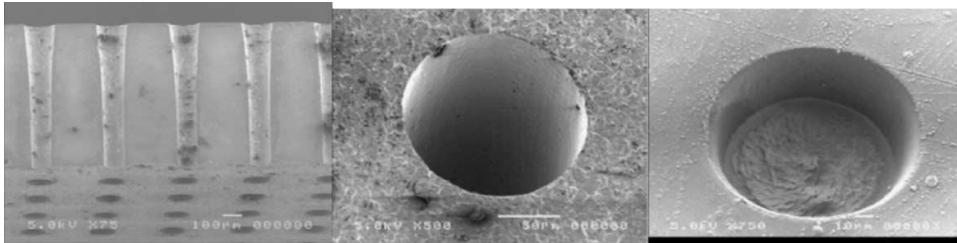
(c) Vaporization



- Since beams typically do not have sharp edges, the diameter can be defined in many different ways
- The most commonly accepted is the $1/e^2$ beam diameter ($e = 2.718$).
- It is measured as the distance between two points on the beam profile that have intensity equal to $1/e^2$ (0.135) of the peak value
- Relation between total power (P_0) and intensity I_0
- $I_0 = \frac{2P_0}{\pi\omega^2}$
- $I(r) = I_0 e^{-\frac{2r^2}{\omega^2}}$



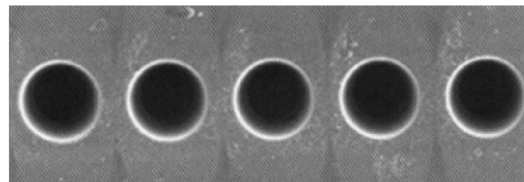
LBM: Applications in machining



Hundred-micrometer holes for medical filters, middle close up of one hole, right blind hole.



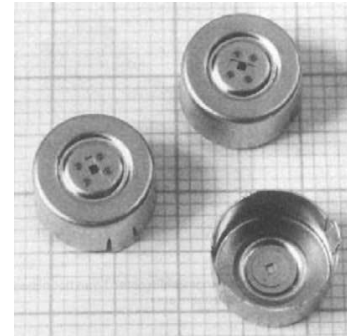
Partial (left) and fully cleaned fine arts, Art-Innovation, NL



Array of ink jet nozzles drilled in 50 μm thick polyimide



- Material Removal : Drilling, Trepanning, cutting
- Material Shaping: Scribing
- Welding
- Thermo kinetic Changes : Heat treatments

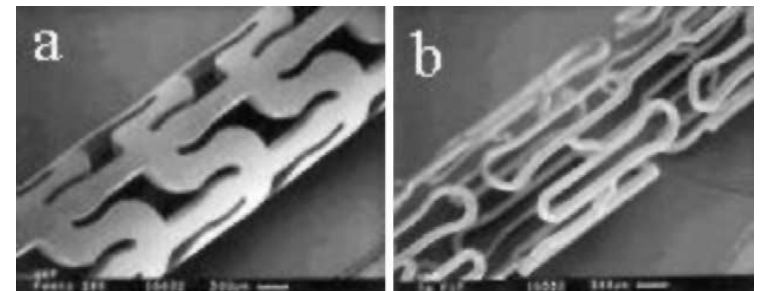


Laser welded parts for a TV electron gun (Philips CFT).

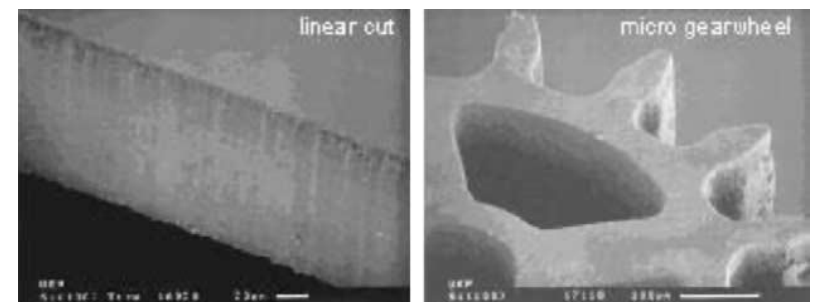


Laser welding of steel (top) on aluminium

Applications of LBM in medical



Prototypes of stents made of: (a) bio-resorbable polymer and (b) tantalum.

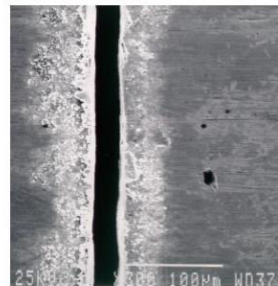
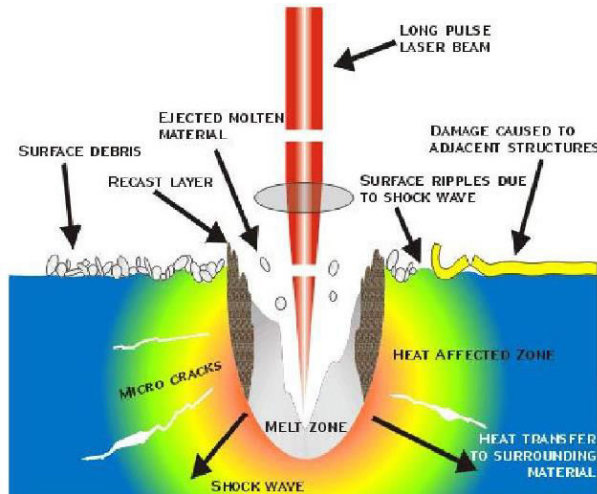


Examples of silicon cutting by Femtosecond laser

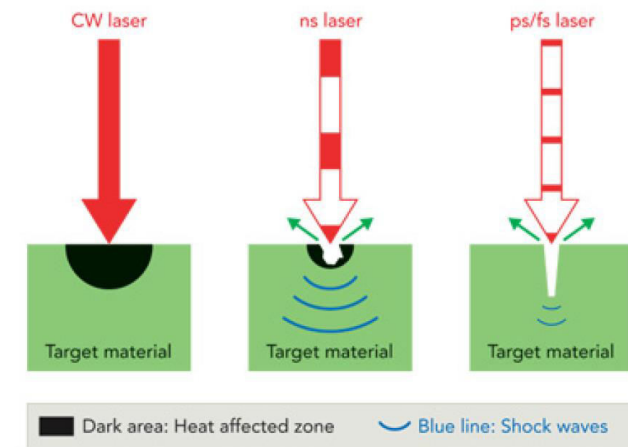


| Laser | Applications | Material |
|--|--|---|
| Micro-electronics packaging | | |
| Excimer | Via drilling and interconnect drilling | Plastics, ceramics, silicon |
| Lamp-pumped solid-state | Via drilling and interconnect drilling | Plastics, metal, ceramics, silicon |
| Diode-pumped solid-state | High volume via drilling, tuning quartz oscillators | Plastics, metal, inorganic |
| CO ₂ sealed or TEA | Excising and scribing of circuit devices, large panel via drilling | Ceramics, plastics |
| Semiconductor manufacturing | | |
| Excimer | UV-lithography IC repair, thin films, wafer cleaning | Resist, plastics, metals, oxides silicon |
| Solid-state | IC repair, thin films, bulk machining resistor and capacitor trimming | Plastics, silicon, metals, oxides silicon, thick film |
| CO ₂ or TEA | Excising, trimming | Silicon |
| Data-storage devices | | |
| Excimer | Wire stripping air bearings, heads micro via drilling | Plastics, glass silicon ceramics plastics |
| Diode-pumped solid-state | Disk texturing servo etching micro via drilling | Metal, ceramics metals, plastic |
| CO ₂ or TEA | Wire stripping | Plastics |
| Medical devices | | |
| Excimer | Drilling catheters balloons, angioplasty devices. Micro-orifice drilling | Plastics, metals ceramics, inorganics |
| Solid-state | Stents, diagnostic tools | Metals |
| CO ₂ or TEA | Orifice drilling | Plastics |
| Communication and computer peripherals | | |
| Excimer | Cellular phone, fiber gratings, flat panel annealing, ink jet heads | Plastics, silicon, glass, metals, inorganics |
| Solid-state | Via interconnect coating removal tape devices | Plastics, metals, oxides, ceramics |
| CO ₂ or TEA | Optical circuits | Glass, silicon |

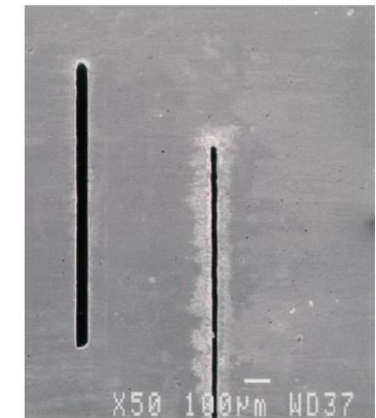
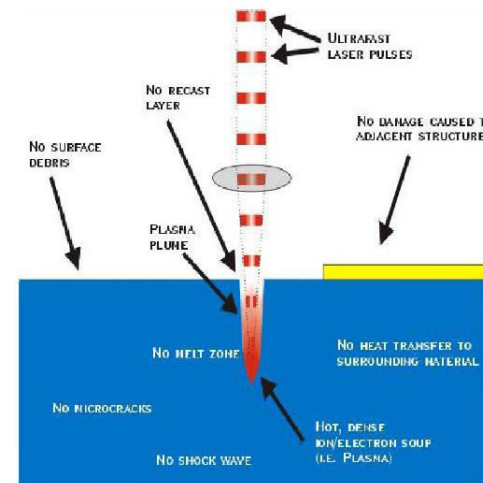
Long Pulsed Laser



- The pulse duration is 8 ns and the energy 0.5 mJ. Example of a 25 μm channel machined in 1 mm thick INVAR with a nanosecond laser.
- Recast layer, heat affected zone, more melting



Short or ultrashort pulse Laser

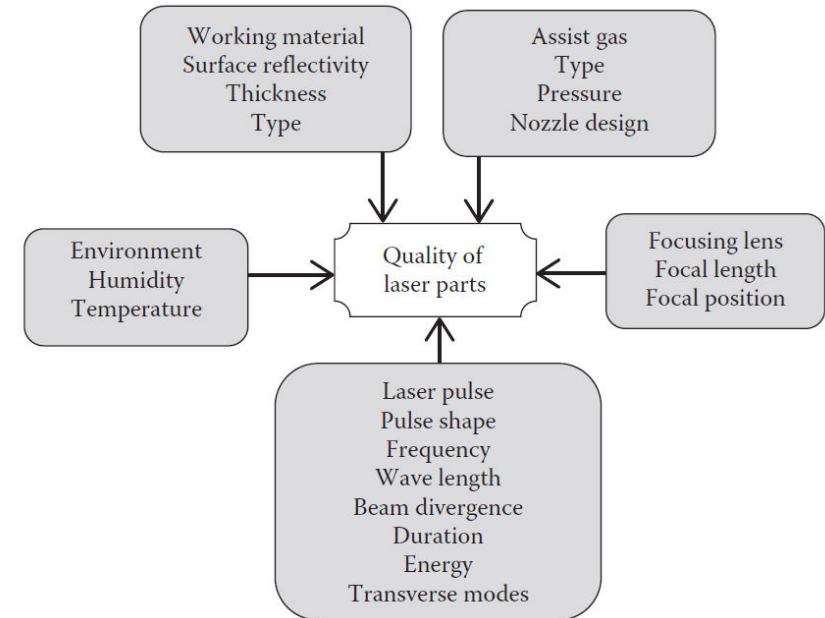
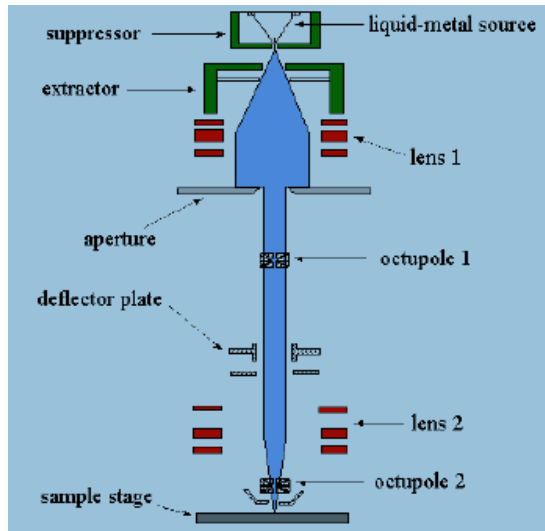


- Less surface damage and recast layer
- Less melting, instant vaporization, deep hole machining



- Advantages:
 - Tool wear and breakage are not encountered.
 - Holes are located accurately by using optical laser system for alignment.
 - Very small holes of large aspect ratio are produced.
 - A wide variety of hard and difficult-to-machine materials are tackled.
 - Machining is extremely rapid and the setup times are economical.
 - Holes can be drilled at difficult entrance angles (108 to the surface).
 - Due to its flexibility, the process can be automated easily.
 - The operating cost is low.
- Limitations
 - The equipment cost is high.
 - Tapers are normally encountered in the direct drilling of holes.
 - A blind hole of precise depth is difficult to achieve with a laser beam.
 - Adherent material, which is found normally at the exit holes, needs to be removed.

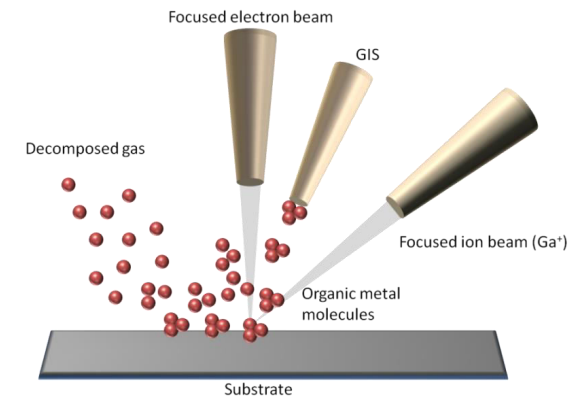
Focused Ion Beam Machining

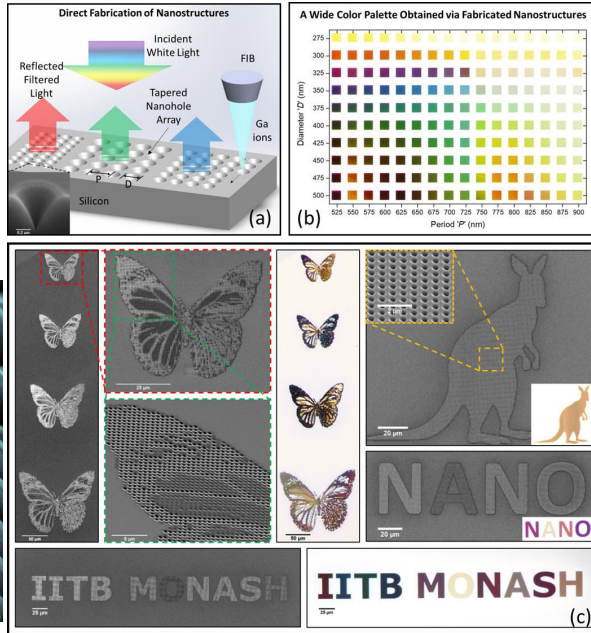
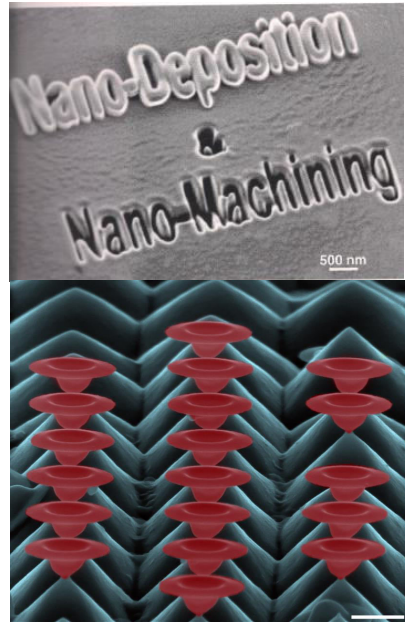


Focused Ion beam machining (FIB)



- Ga^+ ion beam raster over the surface similar to SEM
- Milling of small holes and modifications in the structures can be done
- Most instruments combine nowadays a SEM and FIB for imaging with high resolution, and accurate control of the progress of the milling
- Process is performed in vacuum





*Prof. Rakesh Mote research work

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- FIB finds application in:
 - Ablation of hard materials: diamond, WC
 - Polishing of single crystals
 - Deposition
 - Site-specific analysis
 - FIB lithography
 - TEM samples
- Capital investment ~ 5 Crore

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